

Ultra-Low Capacitance ESD Diode Array

- Rail-to-rail diodes with internal TVS diode
- ESD / transient protection of four I/O lines and one Vcc line exceeding:

IEC61000-4-2 (ESD): ± 15 kV (contact)

IEC61000-4-4 (EFT): 2.5 kV / 50 A (5/50 ns)

IEC61000-4-5 (surge): 3 A (8/20 μs)

- Reverse working voltage data lines: 5.3 V max.
- Reverse working voltage Vcc: 6 V max.
- Very low capacitance: 0.4 pF typ.
- Very low reverse current < 10 nA typ.
- Very low clamping voltage:
 - 12 V typ. at positive transients
 - 4 V typ. at negative transients
- Pb-free (RoHS compliant) package

Applications

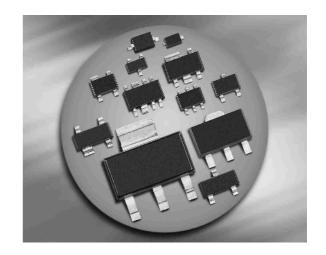
- USB 2.0 ports and future USB 3.0 ports
- Ethernet port: 10/100/1000 Mb/s
- IEEE 1394 FireWire ports
- Mobile communications e.g. high-speed SIM card protection
- Consumer products (STB, DVD, DSC, DVC...)
- Notebooks and desktop computers, peripherals



ESD5V3U4RRS



Туре	Package	Configuration	Marking
ESD5V3U4RRS	SOT363	6 pins, uni-directional	E8s





Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD contact discharge ¹⁾	V _{ESD}	15	kV
Peak pulse current $(t_p = 8 / 20 \mu s)^2)$	I _{pp}	3	А
Peak pulse power $(t_p = 8 / 20 \mu s)^2$	P_{pk}	50	W
Operating temperature range	T_{op}	-55125	°C
Storage temperature	T _{stg}	-65150	

Electrical Characteristics at T_{Δ} = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics ³⁾	•				•
Reverse working voltage	V_{RWM}				V
I/O pin ⁴⁾ to pin 5		-	-	5.3	
pin 2 to pin 5		-	-	6	
Breakdown voltage	V _(BR)	6.3	-	-	
$I_{(BR)}$ = 1 mA, any pin to pin 5	, ,				
Reverse current	I _R	-	< 10	100	nA
V_{R} = 5.3 V, any pin to pin 5					
Clamping voltage	V_{CL}				V
I_{PP} = 1 A, t_p = 8/20 µs ²⁾ , any pin to pin 5		-	10	13	
$I_{PP} = 3 \text{ A}, t_p = 8/20 \mu\text{s}^{2}$, any pin to pin 5		-	12	15	
Forward clamping voltage	V_{FC}				
I_{PP} = 1 A, t_{p} = 8/20 µs ²⁾ , any pin to pin 5		-	2	4	
$I_{PP} = 3 \text{ A}, t_p = 8/20 \ \mu\text{s}^{2}$, any pin to pin 5		-	4	6	
Line capacitance ⁵⁾⁴⁾	C _T	-	0.4	0.6	pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}, \text{ any I/O pin to pin 5}$					
Dynamic resistance ⁶⁾	R _D	-	-	-	-

 $^{^{1}}V_{\mathrm{ESD}}$ according to IEC61000-4-2

 $^{^2}I_{\rm pp}$ according to IEC61000-4-5

³It is strongly recommended that pin 5 is connected to ground for propper functionality.

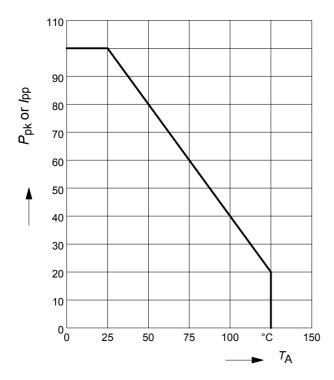
⁴I/0 pins are pin 1, 3, 4, 6

⁵Total capacitance line to ground

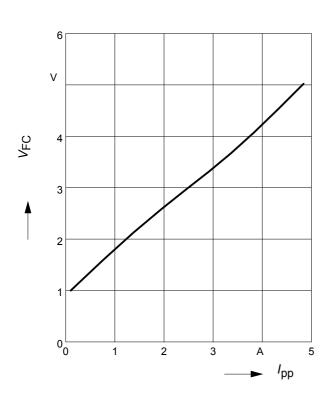
⁶ according to TLP tests



Power derating curve $P_{pk} = f(T_A)$

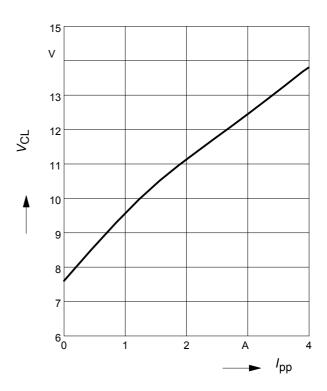


Forward clamping voltage $V_{\rm FC}$ = $f(I_{\rm PP})$ $t_{\rm p}$ = 8 / 20 $\mu {\rm s}$



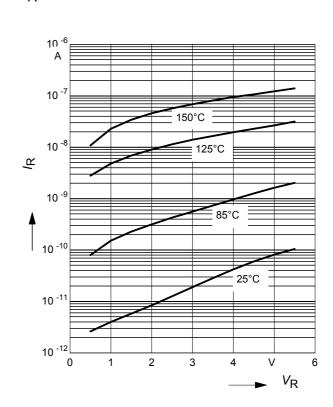
Clamping voltage, $V_{cl} = f(I_{pp})$

$$t_{\rm p}$$
 = 8 / 20 $\mu {\rm s}$



Reverse current $I_R = f(V_R)$

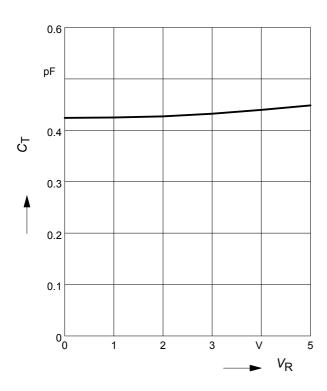
$$T_A$$
 = Parameter





Diode capacitance $C_T = f(V_R)$

f = 1MHz

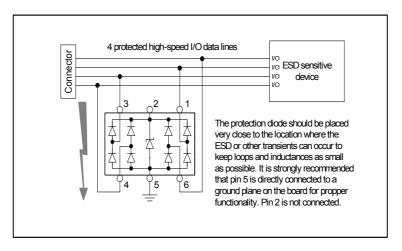


4



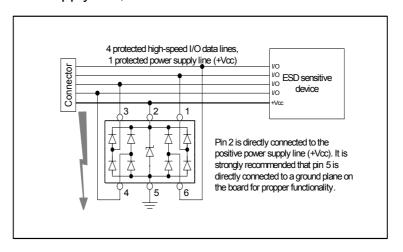
Application example ESD5V3U4RRS

4 data lines, uni-directional



Application example ESD5V3U4RRS

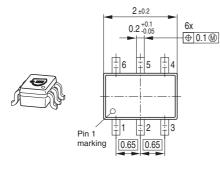
4 data lines and 1 power supply line, uni-directional

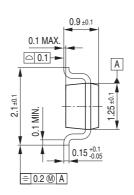


5 2011-06-17

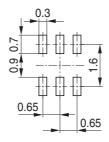


Package Outline



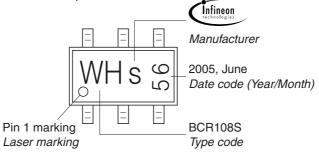


Foot Print



Marking Layout (Example)

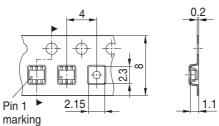
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



6



Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

© 2009 Infineon Technologies AG All Rights Reserved.

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (<www.infineon.com>).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

7